

HMC399MS8 / 399MS8E

v04.1208





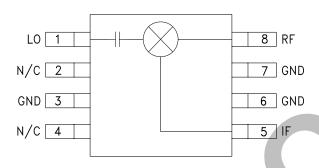
HIGH IP3 GaAs MMIC MIXER, 700 - 1000 MHz

Typical Applications

High Dynamic Range Infrastructure:

- GSM, GPRS & EDGE
- CDMA & W-CDMA
- Cable Modem Termination Systems

Functional Diagram



Features

+35 dBm Input IP3

Conversion Loss: 8.5 dB Low External Part Count

Ultra Small MSOP8 Package: 14.8 mm² Included in the HMC-DK003 Designer's Kit

General Description

The HMC399MS8(E) is a high dynamic range passive MMIC mixer in plastic surface mount 8 lead Mini Small Outline Package (MSOP) covering 700 to 1000 MHz. Excellent input IP3 performance of +35 dBm for down conversion and +32 dBm for up conversion is provided for 2.5G & 3G GSM/ CDMA based cellular applications at an LO drive of +17 dBm. With a 1 dB compression of +23 dBm, the RF port will accept a wide range of input signal levels. Conversion loss is 8.5 dB typical and LO isolations are maintained at 23 to 35 dB. This miniature single-ended monolithic GaAs FET mixer requires only one external inductor to optimize the LO frequency response. The 50 to 250 MHz IF frequency response will satisfy many cellular transmit or receive frequency plans. HMC399MS8(E) input IP3 performance coupled with its high P1dB rivals traditional active FET mixers while offering a much smaller 14.8mm² standard IC footprint and no DC bias.

Electrical Specifications, $T_A = +25$ °C, LO = +17 dBm, IF = 200 MHz [1]

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range, RF		740 - 800			800 - 900		880 - 960		MHz	
Frequency Range, LO [2]		540 - 740			550 - 840		630 - 900		MHz	
Frequency Range, IF		DC - 200			DC - 250		DC - 250		MHz	
Conversion Loss		9	10		8.5	9.5		8	10	dB
Noise Figure (SSB)		9	10		8.5	9.5		8	10	dB
LO to RF Isolation	19	23		20	24		21	25		dB
LO to IF Isolation	22	27		26	31		29	35		dB
IP3 (Input)	30	34		31	35		30	34		dBm
1 dB Gain Compression (Input)	20	24		19	23		18	22		dBm
LO Input Drive Level (Typical)	+16 to +18			+16 to +18		+16 to +18		dBm		

^[1] Unless otherwise noted, all measurements performed as a downconverter with low side LO & IF = 200 MHz

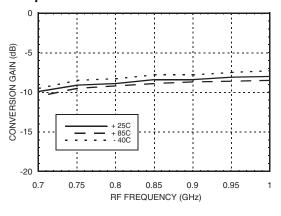
^[2] LO Frequency optimized. See application circuit herein.



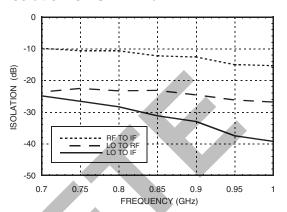


HIGH IP3 GaAs MMIC MIXER, 700 - 1000 MHz

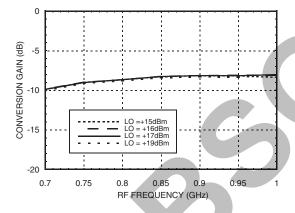
Conversion Gain vs.
Temperature @ LO = +17 dBm



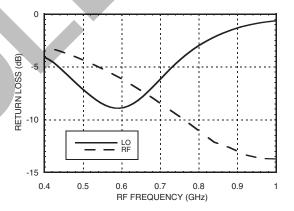
Isolation @ LO = +17 dBm



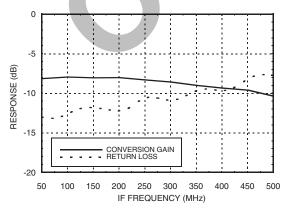
Conversion Gain vs. LO Drive



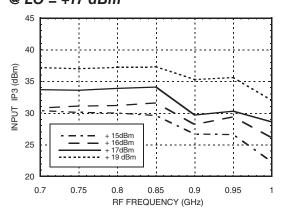
Return Loss @ LO = +17 dBm*



If Bandwidth @ LO = +17 dBm



Upconverter Conversion Gain @ LO = +17 dBm



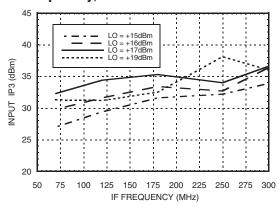
HIGH IP3 GaAs MMIC MIXER, 700 - 1000 MHz



v04.1208

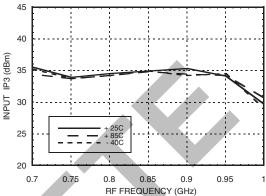


Input IP3 vs. IF Frequency, RF = 850 MHz

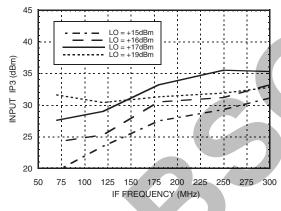


Temperature @ LO = +17 dBm

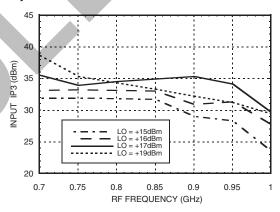
Input IP3 vs.



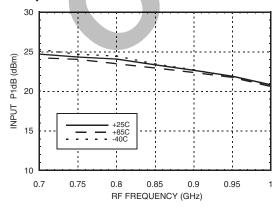
Input IP3 vs. IF Frequency, RF = 950 MHz



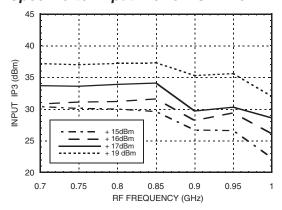
Input IP3 vs. LO Drive



Input P1dB vs. Temperature @ LO = +17 dBm



Upconverter Input IP3 vs. LO Drive

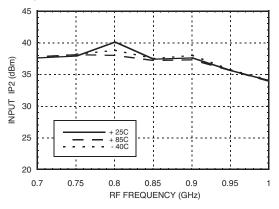




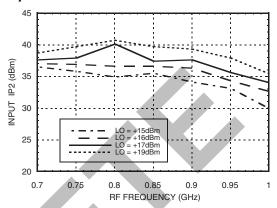


HIGH IP3 GaAs MMIC MIXER, 700 - 1000 MHz

Input IP2 vs. Temperature @ LO = +17 dBm



Input IP2 vs. LO Drive



MxN Spurious Outputs

	nLO				
mRF	0	1	2	3	4
0	xx	-9	17	2	23
1	3	0	17	28	26
2	69	75	57	62	65
3	80	71	82	69	80
4	81	81	81	80	80

RF Freq = 0.801 GHz @ -10 dBm LO Freq = 0.601 GHz @ +17 dBm

All values in dBc relative to the IF power level.

Harmonics of LO

	nLO Spur @ RF Port				
LO Freq (GHz)	1	2	3	4	
0.4	34	54	38	45	
0.5	30	39	35	47	
0.6	26	35	33	54	
0.7	24	37	36	47	
0.8	23	33	42	50	
0.9	25	31	46	43	

IO = +17 dBm

All values are in dBc below input LO level @ RF port.





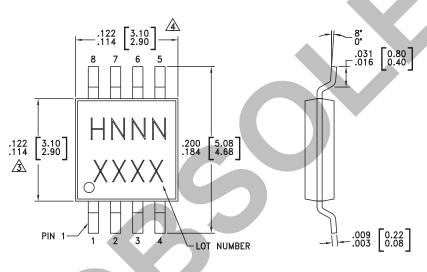
HIGH IP3 GaAs MMIC MIXER, 700 - 1000 MHz

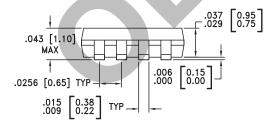
Absolute Maximum Ratings

RF/IF Input	+25 dBm
LO Drive	+27 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
IF DC Current	±40 mA



Outline Drawing





NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3 DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- 4 DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC399MS8	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H399 XXXX
HMC399MS8E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	<u>H399</u> XXXX

- [1] Max peak reflow temperature of 235 $^{\circ}\text{C}$
- [2] Max peak reflow temperature of 260 $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.





HIGH IP3 GaAs MMIC MIXER, 700 - 1000 MHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	LO	This pin is AC coupled & matched to 50 Ohms when an external inductor (L1) is connected in series with the LO. Choose value of L1 to optimize LO frequency response.	roo-1-1-1
2, 4	N/C	Not connected.	
3, 6, 7	GND	This pin must be connected to RF ground.	GND
5	IF	This pin is DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor. Choose value of C1 to pass IF frequency desired. For operation to DC, this pin must not sink/source more than 40 mA of current or failure may result.	
8	RF	This pin is DC coupled & matched to 50 Ohms from 700 - 1000 MHz	RF O

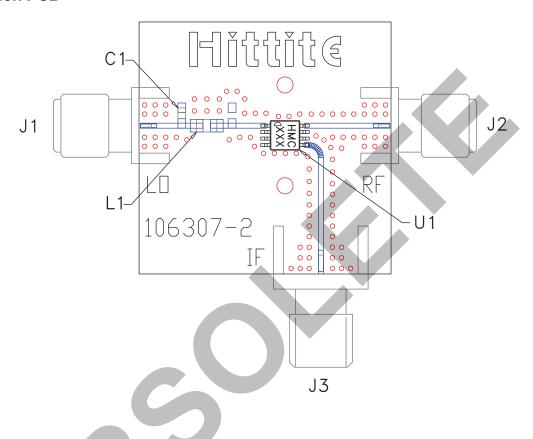






HIGH IP3 GaAs MMIC MIXER, 700 - 1000 MHz

Evaluation PCB



List of Materials for Evaluation PCB 106334 [1]

Item		Description		
J1 - J3		PCB Mount SMA RF Connector		
C1		4 pF Capacitor, 0603 Pkg.		
L1		24 nH Chip Inductor, 0805 Pkg		
U1		HMC399MS8 / HMC399MS8E Mixer		
PCB [2]		106307 Eval Board		

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

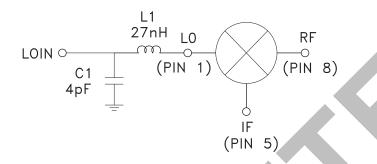
The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.





HIGH IP3 GaAs MMIC MIXER, 700 - 1000 MHz

Application Circuit



Selection of L1 for Optimal LO Frequency ±10%

Choose value of L1 to optimize LO Frequency response. For best results use an 0805 size RF inductor or smaller.

IF (MHz)	LO Frequency (MHz)	L1 (nH)	C1 pF
250	600	27	4
170	700	22	4
100	800	18	5
70	850	15	5

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Mixer category:

Click to view products by Analog Devices manufacturer:

Other Similar products are found below:

 HMC337-SX
 HMC404-SX
 mamx-009646-23dbml
 HMC339-SX
 HMC8192-SX
 MIQ24MS-2
 HMC220BMS8GETR
 M85C
 HMC554A-SX

 HMC8192LG
 HMC521A-SX
 HMC521ACHIPS
 CMD258C4
 LT5511EFE
 MAMX-011023-SMB
 HMC399MS8TR
 HMC333TR

 HMC214MS8TR
 HMC175MS8TR
 MAMXSS0012TR-3000
 109728-HMC129LC4
 CSM1-13
 SA612AD/01.112
 HMC785LP4ETR

 LT5579IUH#PBF
 HMC773ALC3BTR
 HMC558ALC3B
 HMC329ALC3B
 MY63H
 AD8343ARUZ-REEL7
 AD608AR
 AD608AR

 AD831APZ
 AD831APZ-REEL7
 AD8342ACPZ-REEL7
 AD8343ARUZ
 AD8344ACPZ-REEL7
 ADL5350ACPZ-R7
 ADL5363ACPZ-R7

 ADL5365ACPZ-R7
 ADL5801ACPZ-R7
 ADL5802ACPZ-R7
 HMC1056LP4BE
 HMC1057-SX
 HMC1063LP3E
 HMC1093-SX
 HMC1106-SX

 SX
 HMC129
 HMC143
 HMC400MS8ETR